LONG



Advanced Technology Integration LR5-72HGD-565~580M



Product parameters

Hi-MO 7

Pmp (W)	565	570	575	580
Voc (V)	51.09	51.19	51.30	51.41
lsc (A)	13.97	14.05	14.14	14.22
Vmp(V)	42.91	43.00	43.11	43.22
Imp (A)	13.17	13.26	13.34	13.42
Temperature Coefficient of Pmax	-0.28%/°C			
Power warranty	First year power degradation $\leqslant 0.8\%$, linear degradation $\leqslant 0.38\%$ /year			

STC (Standard Testing Configuration) : irradiance1000W/m2, cell temperature25°C, spectrum AM1.5

Efficiency at its best Hi-MO 7

Technology Revolution Founder in Mono-Si PV Industrial Efficiency Record Holder of Crystalline Silicon PV Cell Global Champion in PV Module Shipment (2019~2022)

Advanced Technology Integration



HPDC cell technology



sivation property has been enhanced, resulting in a reduction of the dark saturation current J0 and an improvement in Voc, which optimizes the power temperature coefficient and low light performance

Optimize and control the thickness of high and low BSF film, reduce light absorptior and improve the bifaciality ratio of the cell

Hybrid Passivated Dual-Junction Cell, which is a bifacial dual-junction cell produced by hybrid passivation technology . Different passivation technologies are used on the front and back of this cell, which can effectively reduce the carrier recombination and enhance the cell's power generation capacity. Meanwhile, the high and low junctions on the backside can realize full passivation and further reduce surface recombination. Therefore, HPDC cell has higher Voc and efficiency, lower degradation and better power temperature coefficient.

HPDC is name for High Performance and

The deposition process for high and low nctions was optimized, with controlled ration differences resulting in reduced contact resistance or and improved cell efficiency

High performance-the third party testing result



Won the prize of 2022 Energy **Yield Simulation from All Quality Matters**

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Power temperature coefficient Low light performance IAM performance





The excellent power generation performance of the product has been verified by Hainan Demonstration Power Station of CEI

Hi-MO 7

LONGi Lifecycle Quality guarantees long term reliability of products

Grade A+ silicon wafer quality Low impurity

ML

LID

SMBB technology Nondestructive cutting

Product Value

Better Temperature Coefficient

Better temperature coefficient benefits from Hi-MO7's better passivation performance and higher Voc, About 1% increase in power generation in high temperature environment





DH



PID

LONGI LIFECYCLE QUALITY **High reliability** automatic welding

Encapsulation system optimization

Higher Bifaciality

Benefits from Hi-MO 7's higher bifaciality of 80%, the bifacial gain is improved by 1%+

Mainstream product

Hi-MO 7

Bifaciality ~70% Bifacial gain 9%

~80%



The power generation performance of bifacial module is significantly improved